

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	30	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 5) VGS = 10V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	ID	220 170	mA
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	260 210	mA
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation	(Note 5)	Pn	300	mW	
Total Power Dissipation	(Note 6)	PD	400		
Thermal Resistance, Junction to Ambient	(Note 5)	D	435		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	330	°C/W	
Thermal Resistance, Junction to Case	(Note 6)	R _θ JC	139		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

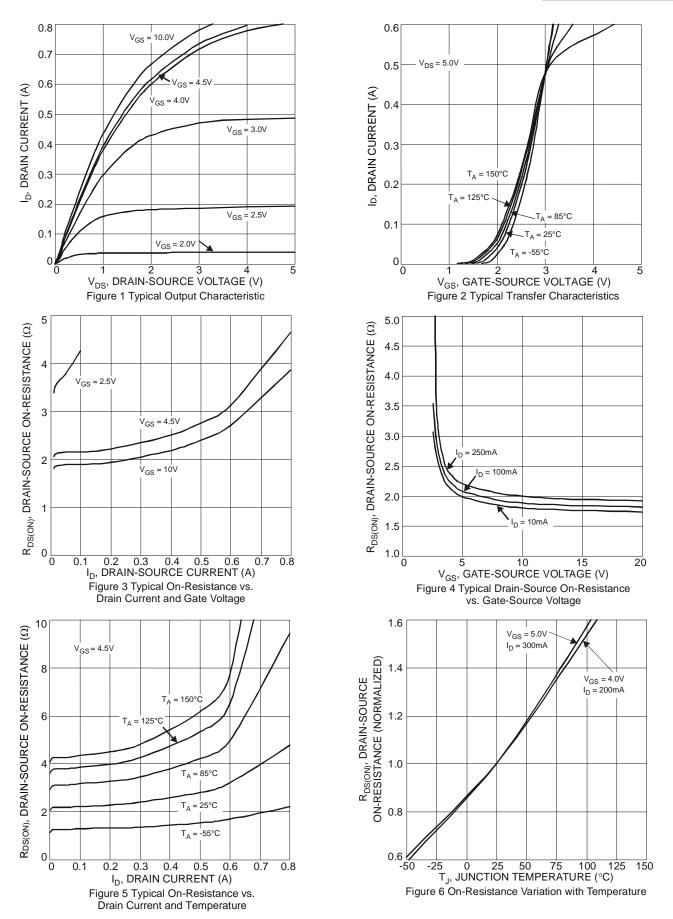
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1.0	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Body Leakage	Igss			±10.0	μΑ	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	0.8		1.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
				2.8	Ω	$V_{GS} = 10.0V, I_D = 250mA$	
				3.8		$V_{GS} = 5V, I_{D} = 250mA$	
Static Drain-Source On-Resistance	RDS(ON)	_		4.2		V _{GS} = 4.5V, I _D = 250mA	
				4.5		V _G S = 4.0V, I _D = 250mA	
	-			13		V _{GS} = 2.5V, I _D = 10mA	
Forward Transconductance	g FS	80		_	mS	V _{DS} = 10V, I _D = 0.115A	
Diode Forward Voltage	VsD		0.8	1.2	V	V _G S = 0V, I _S = 115mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		22.0	_			
Output Capacitance	Coss		3.2	_	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	Crss	_	2.0	_			
Gate Resistance	Rg	_	79.9	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	0.87	_			
Total Gate Charge (VGS = 4.5V)	Qg	_	0.43	_		\/ 20\/ I- 450mA	
Gate-Source Charge	Qgs		0.11	_	nC	$V_{DS} = 30V, I_{D} = 150mA$	
Gate-Drain Charge	Qgd		0.11	_			
Turn-On Delay Time	td(ON)	_	3.3	_			
Turn-On Rise Time	t _R	_	3.2	_		V _{DD} = 30V, I _D = 0.115A, V _{GEN} = 10V,	
Turn-Off Delay Time	tD(OFF)	_	12.0	_	ns	$R_{GEN} = 25\Omega$	
Turn-Off Fall Time	t _F		6.3				

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
- 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.







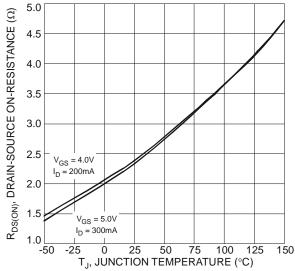
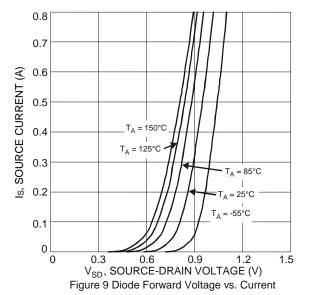


Figure 7 On-Resistance Variation with Temperature



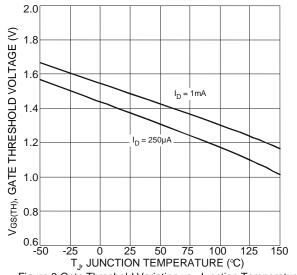


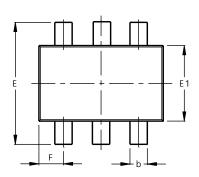
Figure 8 Gate Threshold Variation vs. Junction Temperature

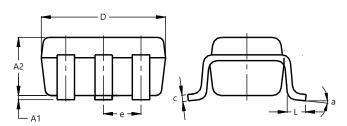


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363 (Standard)



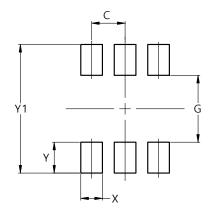


SOT363 (Standard)					
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.80	1.00	0.90		
b	0.10	0.35	0.225		
С	0.08	0.22	0.15		
D	1.80	2.20	2.00		
Е	2.00	2.45	2.225		
E1	1.15	1.35	1.25		
е			0.65		
F	0.25	0.45	0.35		
L	0.25	0.46	0.355		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363 (Standard)



Dimensions	Value (in mm)			
С	0.650			
G	1.300			
Х	0.420			
Y	0.600			
Y1	2.500			



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